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PATENT APPLICATION

TATENT ATTECATION

ATTORNEY DOCKET NO. __10007799 -1

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Xia Sheng et al

Confirmation No.: 3212

Application No.: 09/845845

Examiner: Santiago, Maricel

Filing Date:

itor(s):

Apr 30, 2001

Group Art Unit:

Title:

Silicon Emitter With Low Porosity Heavily Doped Contact Layer

Commissioner for Patents PO Box 1450 Alexandria, VA 22313-1450

TRANSMITTAL LETTER FOR RESPONSE/AMENDMENT

Sir:				
Trans	smitted herewith is	are the following in the a	bove-identified app	olication:
(X)	Response/Amendr	nent	()	Petition to extend time to respond
()	New fee as calcula	ated below	()	Supplemental Declaration
()	No additional fee	(Address envelope to "I	Mail Stop Non-Fee	Amendment")
()	Other:	<u> </u>		(fee \$)

(7) ADDITIONAL FEES \$ 0		(6) RATE		(5) PRESENT EXTRA		(4) HIGHEST NUMBER PREVIOUSLY PAID FOR		(3) NUMBER EXTRA	(2) CLAIMS REMAINING AFTER AMENDMENT		(1) FOR	
		\$18	×	0	=	39		MINUS	4	•	TOTAL CLAIMS	
		\$86	×	0	=	3		MINUS	3		INDEP. CLAIMS	
\$,	\$290	[] FIRST PRESENTATION OF A MULTIPLE DEPENDENT CLAIM + \$290									
;				ON 1ST MONTH 2ND MONTH 3RD MONTH 4TH MON \$110.00 \$420.00 \$950.00 \$1480.0		EXTENSION FEE						
	\$	OTHER FEES										
>	,	IENT	TOTAL ADDITIONAL FEE FOR THIS AMENDMENT									

Charge \$ 0 to Deposit Account 08-2025. At any time during the pendency of this application, please charge any fees required or credit any overpayment to Deposit Account 08-2025 pursuant to 37 CFR 1.25. Additionally please charge any fees to Deposit Account 08-2025 under 37 CFR 1.16 through 1.21 inclusive, and any other sections in Title 37 of the Code of Federal Regulations that may regulate fees. A duplicate copy of this sheet is enclosed.

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, Alexandria, VA 22313-1450.

Date of Deposit: March 31, 2004

Typed Name: Alba P. Escobar

Typed Name. Alba P Escobar

Xia Sheng et al

Respectfully submitted,

Trueman H Denny ∕∰

Attorney/Agent for Applicant(s)

Reg. No. 44,652

Date: March 31, 2004

Telephone No.: 650 857 3870

- Attach as First Page to Transmitted Papers -

Signature

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In reapplication of: Xia Sheng, et al.

Docket No.: 10007799-1

PApplication No.: 09/845,845

Group Art Unit: 2879

Filed: 04/30/2001

Examiner: Santiago, Mariceli

Title: SILICON EMITTER WITH LOW POROSITY HEAVILY DOPED CONTACT

LAYER

AMENDMENT AND RESPONSE UNDER 35 U.S.C. §121 and 37 C.F.R. §1.111

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

This amendment is responsive to an Office Action, mailed **31 December 2003**, for the above-identified patent application.

AMENDMENT

Please Amend the above-identified patent application as follows:

Amendments to the Claims are reflected in the <u>Claims Listing</u> which begins on *Page 2* of this response.

Remarks/The Present Amendment begin on *Pages 12* and *13* respectively of this response.

A Conclusion begins on *Page 15* of this response.